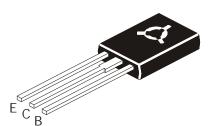


Continental Device India Limited An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

NPN SILICON POWER TRANSISTOR



CR13003



TO126 Plastic Package

Suitable for Lighting, Switching Regulator and Motor Control

ABSOLUTE MAXIMUM RATINGS			
DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Base Voltage	V _{CBO}	700	V
Collector Emitter (sus) Voltage	V _{CEO}	400	V
Emitter Base Voltage	V _{EBO}	9.0	V
Collector Current Continuous	Ι _C	1.5	А
Peak (1)	I _{CM}	3.0	А
Base Current Continuous	I _B	0.75	А
Peak (1)	I _{BM}	1.5	А
Emitter Current Continuous	Ι _Ε	2.25	А
Peak (1)	I _{EM}	4.5	А
Power Dissipation at T _a =25 °C	PD	1.4	W
Derate Above 25ºC		11.2	mW/ ⁰C
Power Dissipation at T _c =25 °C	PD	40	W
Derate Above 25°C		320	mW/ °C
Operating And Storage Junction	тт	- 65 to+150	°C
Temperature Range	T_{j},T_{stg}	- 03 (0+150	

THERMAL RESISTANCE

Junction to Case	R _{th (j-c)}	3.12	°C/W
Junction to Ambient	R _{th (j-a)}	89	°C/W
Maximum Lead Temperature for Soldering Purpose: 1/8" from Case for 5 Seconds	T_{L}	275	٥C

(1) Pulse Test: Pulse Width=5ms, Duty Cycle=10%

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

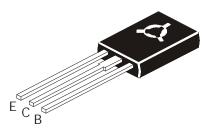
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Base Voltage	V _{CBO}	I _C =1mA, I _E =0	600			V
Collector Emitter (sus) Voltage	*V _{CEO(sus)}	I _C =10mA, I _B =0	400			V
Collector Cut Off Current	I _{CBO}	V _{CB} =700V, I _E =0			1.0	mA
		V_{CB} =700 $V_{,}I_{E}$ =0, T_{c} =100°C			5.0	mA
Emitter Cut Off Current	I _{EBO}	V _{EB} =9V, I _C =0			1.0	mA

*Pulse Test: PW=300ms, Duty Cycle=2%

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NPN SILICON POWER TRANSISTOR

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TO126 Plastic Package

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
DC Current Gain	*h _{FE}	**I _C =0.3A, V _{CE} =2V	10		30	
		I _C =0.5A, V _{CE} =2V	8		40	
		I _C =1A, V _{CE} =2V	4		25	
Collector Emitter Saturation Voltage	*V _{CE (sat)}	I _C =0.5A, I _B =0.1A			0.5	V
		I _C =1A, I _B =0.25A			1.0	V
		I _C =1.5A, I _B =0.5A			3.0	V
		I_{C} =1A, I_{B} =0.25A, T_{c} =100°C			1.0	V
Base Emitter Saturation Voltage	*V _{BE (sat)}	I _C =0.5A, I _B =0.1A			1.0	V
		I _C =1A, I _B =0.25A			1.2	V
		I_{C} =1A, I_{B} =0.25A, T_{c} =100°C			1.1	V

DYNAMIC CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Current Gain Bandwidth Product	f⊤	I _C =100mA, V _{CE} =10V, f=1MHz	4.0			MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=0.1MHz		21		pF

SWITCHING TIME

Delay Time	t _d		0.1	μs
Rise Time	t _r	V _{CC} =125V, I _C =1A,	1.0	μs
Storage Time	t _s	$I_{B1} = I_{B2} = 0.2A$, $t_p = 25\mu s$,	4.0	μs
Fall Time	t _f	Duty Cycle=1%	0.7	μs
	-	-	 -	
Voltage Storage Time	tav	$V_{0} = 300 V I_{0} = 1A$	4 00	115

voltage Storage Time	ι _{sv}	V_{Clamp} =300V, I_{C} =1A,		4.00	μs
Crossover Time	t _C	$I_{B1}=0.2A, V_{BE(off)}=5V,$		0.75	μs
Fall Time	t _{fi}	T _c =100°C	0.15		μs

*Pulse Test: PW=300m6, Duty Cycle=2%

** h_{FE} Classification:-

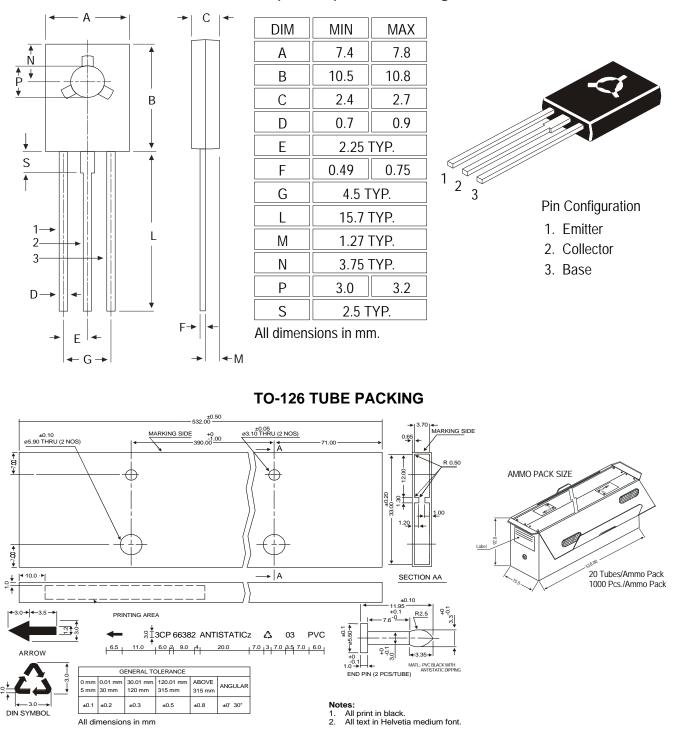
Note:- Product is pre selected in DC current	Α	В	С	E	F
gain (Groups A to F). CDIL reserves the right to ship any of the groups according to production availability.	11-16	15-19	18-22	21-25	24-30
MARKING	CR 13003A XY	CR 13003B XY	CR 13003C XY	CR 13003E XY	CR 13003F XY
X = Year of Manufacturer Code Y = Month Code					

*Pulse Test:- PW=300ms, Duty Cycle=2%

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CR13003 TO126 Plastic Package

TO-126 (SOT-32) Plastic Package



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size Qty Size		Size	Qty	Gr Wt
TO-126 Bulk	500 pcs/polybag	340 gm/500 pcs	3" x 7.5" x 7.5"	2K	17" x 15" x 13.5"	32K	31 kgs
TO-126 Tube	50 pcs/tube	73 gm/50 pcs	3" x 3.7" x 21.5"	1K	19" x 19" x 19"	10K	15 kgs

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Continental Device India Limited

TO126 Plastic Package

Component Disposal Instructions

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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Data Sheet